

BSY 27	Itt,Tix	Si-N	=BSY 26: 19/35ns, hFE=25...120	2a	TO-18			BSV 89...92, BSX 92...93, 2N3011, ++
BSY 28	Itt,Tix	Si-N	SS, 15/12V, 0,1/0,2A, 0,3W, 380MHz,14/22ns, hFE>20	2a	TO-18			BSV 89...92, BSX 44, BSX 92...93, 2N3011++
BSY 29	Itt,Tix	Si-N	=BSX 28: 12/20ns, hFE=40...120	2a	TO-18			BSV 89...92, BSX 44, BSX 92...93, 2N3011++
BSY 30	Sie	Si-N	S, 15/15V, 0,2A, 0,3W, <120/-ns, hFE>20	2a	TO-18			BSW 41, BSY 62...63, 2N706A, 2N4123, ++
BSY 31	Sie	Si-N	=BSY 30: <180/-ns, hFE>30	2a	TO-18			BSW 41, BSY 62...63, 2N706A, 2N4123, ++
BSY 32	Itt	Si-N	S, 20/15V, 0,1A, 0,1W, <27/130ns, >200MHz, hFE=32					BSW 41, BSY 62...63, 2N706A, 2N4123, ++
BSY 33	Itt	Si-N	=BSY 32: hFE=55					BSW 41, BSY 62...63, 2N706A, 2N4123, ++
BSY 34	Phi,Sie	Si-N	S,Drv, 60/40V, 0,6A, 0,8W, 400MHz, 30/50ns	2a	TO-39	(BC 141)	2a	BSS 27, BSV 77, BSV 95, 2SC1385...86, ++
BSY 35	Itt	Si-P	Min, S, 75V, 0,05A	Chip	TO-122			
BSY 36	Itt	Si-N	S, 15/12V, 0,1A, 0,1W, >300MHz, <20/30ns					BSV 89...92, BSX 44, BSX 92...93, 2N3011++
BSY 38(A)	Mot,Phi,Tix	Si-N	=2N743	2a	TO-18			+2N743
BSY 39(A)	Mot,Phi,Tix	Si-N	=2N744	2a	TO-18			+2N744
BSY 40	Mot,Phi,Tix	Si-P	S, 25/20V, 0,1A, 0,3W, 210MHz, <25/100ns, hFE>20	2a	TO-18			2N3250...51, 2N3905...06, 2N4125...26
BSY 41	Mot,Phi,Tix	Si-P	=BSY 40: 230MHz, hFE=50...200	2a	TO-18			2N3250...51, 2N3905...06, 2N4125...26
BSY 42	Itt	Si-N	Dual, 20V, 0,2A, >200MHz	TO-77				
BSY 43	Itt	Si-N	Dual, 15V, 0,2A, >300MHz	TO-77				
BSY 44	Aeg,Mot,Tix	Si-N	=2N1613	2a	TO-5			+2N1613
BSY 45	Aeg,Mot,Tix	Si-N	=2N1893	2a	TO-5			+2N1893
BSY 46	Aeg,Mot,Tix	Si-N	=2N2193	2a	TO-5			+2N2193
BSY 47	Itt	Si-N	S, 20/15V, 0,1A, 0,1W, >200MHz, <27/130ns					BSW 41, BSY 62...63, 2N706A, 2N4124, ++
BSY 48	Sie	Si-N	S, 50/25V, 0,6A, 0,4W, >250MHz, <65/-ns	2a	TO-18			BSV 59, BSX 49, 2N2221...22, 2N3301...02++
BSY 49	Sie	Si-N	S, 60/40V, 0,6A, 0,4W, >250MHz, <50/-ns	2a	TO-18			BSV 59, BSX 49, 2N2221...22, 2N3301...02++
BSY 50	Itt	Si-N	S, 15/12V, 0,1A, 0,1W, >350MHz, <20/30ns					BSV 89...92, BSX 44, BSX 92...93, 2N3011++
BSY 51	EUR	Si-N	L.F.S, 60/25V, 0,5A, 0,8W, 100MHz, hFE=40...120	2a	TO-39	BC 141	2a	BC 140...141, BC 300...302, =2N697, ++
BSY 52	EUR	Si-N	=BSY 51: hFE=100...300	2a	TO-39	BC 141	2a	BC 140...141, BC 300...302, =2N1420, ++
BSY 53	EUR	Si-N	L.F.S, 75/30V, 0,75A, 0,8W, 100MHz, hFE=40...120	2a	TO-39	BC 141	2a	BC 140...141, BC 300...301, =2N1613, ++
BSY 54	EUR	Si-N	=BSY 53: hFE=100...300	2a	TO-39	BC 141	2a	BC 140...141, BC 300...301, =2N1711, ++
BSY 55	EUR	Si-N	L.F.S, 120/80V, 0,5A, 0,8W, 100MHz, hFE=40...120	2a	TO-39			BC 300, BSW 67...68, BSX 47, =2N1893, ++
BSY 56	EUR	Si-N	=BSY 55: hFE=100...300	2a	TO-39			BC 300, BSW 67...68, BSX 47, 2N1893, ++
BSY 58	Phi,Sie	Si-N	S,Drv, 50/25V, 0,6A, 0,8W, 400MHz, 35/65ns	2a	TO-39			BSS 27...29, BSV 77, 2N3724A, 2SC1386, ++
BSY 59	Sie	Si-P	S, 30/30V, 0,8A, 0,28W, 100MHz, <500/850ns	11a	SOT-25			BC 327...328, BC 636, 2N2906...2907, ++
BSY 61(Y)	Sie	Si-N	S, 25V, 0,2A(Y=50mA), 0,2W, >200MHz, <40/75ns	7c	TO-92			BSW 41, BSY 62...63, 2N706A, 2N4124, ++
BSY 62(A,B)	Sie,Tix	Si-N	S, 25/15V, 0,2A, 0,35W, >280MHz, <40/75ns	2a	TO-18			BSW 41, =2N706A, 2N708, 2N4123...24, ++
BSY 63	Phi,Sie,Tix	Si-N	S, 40/15V, 0,2A, 0,35W, >300MHz, <40/75ns	2a	TO-18			BSW 41, =2N708, 2N3903...04, 2N4123, ++
BSY 65	Itt	Si-N	L.F.S, 15V, 0,1A, 0,3W, 200MHz	2a	TO-18			BC 548, BCY 58...59, BSW 41, 2N706A, ++
BSY 66	Itt	Si-N	10V, 0,05W					
BSY 67	Itt	Si-N	10V, 0,05W					
BSY 68	Phi,Tix	Si-N	Nixie Drv, 120/80V, 0,05A, 0,6W, >20MHz	2a	TO-39			BF 257...259, BF 657...659, 2N5058...5059
BSY 70	Aeg,Mot,Tix	Si-N	=2N706	2a	TO-18			+2N706
BSY 71	Aeg,Mot,Tix	Si-N	=2N1711	2a	TO-5			+2N1711
BSY 72	Itt,Tix	Si-N	L.F.S, 25/18V, 0,03A, 0,3W, 170MHz, F<5dB(1kHz)	2a	TO-18			BC 169, BC 184, BC 239, BC 549, 2SC2675+
BSY 73	Itt,Tix	Si-N	L.F.S, 25/18V, 0,1A, 0,3W, 145MHz, F<12dB(1kHz)	2a	TO-18			BC 168, BC 183, BC 238, BC 548, 2SD767++
BSY 74	Itt,Tix	Si-N	L.F.S, 25/18V, 0,1A, 0,3W, 170MHz, F<12dB(1kHz)	2a	TO-18			BC 168, BC 183, BC 238, BC 548, 2SD767
BSY 75	Itt,Tix	Si-N	L.F.S, 40/32V, 0,25A, 0,3W, 145MHz, F<12dB(1kHz)	2a	TO-18			BC 167, BC 182, BC 237, BC 547, 2SD767++
BSY 76	Itt,Tix	Si-N	=BSY 75: 170MHz	2a	TO-18			BC 167, BC 182, BC 237, BC 547, 2SD767++
BSY 77	Itt,Tix	Si-N	=BSY 75: 80/64V	2a	TO-18			BC 546, 2SC2240, 2SC2459, 2SC2674...75,++
BSY 78	Itt,Tix	Si-N	=BSY 75: 80/64V, 170MHz	2a	TO-18			BC 546, 2SC2240, 2SC2459, 2SC2674...75,++
BSY 79	Itt,Tix	Si-N	Nixie Drv, 120V, 0,03A, 0,3W, 100MHz	2a		BF 420 A	7c	BF 297...299, BF 422, BSS 38, BSX 21, ++
BSY 80	Itt,Tix	Si-N	L.F.S, 25/18V, 0,1A, 0,3W, 210MHz, F<12dB(1kHz)	2a	TO-18			BC 168, BC 183, BC 238, BC 548, 2SD767++
BSY 81	Itt,Tix	Si-N	L.F.S, 40/18V, 1A, 0,9W, 100MHz, hFE=40...120	2a	TO-39	BC 141	2a	BC 140...141, BSW 65...68, BSX 45...47, ++
BSY 82	Itt,Tix	Si-N	=BSY 81: 120MHz, hFE=100...300	2a	TO-39	BC 141	2a	BC 140...141, BSW 65...68, BSX 45...47, ++
BSY 83	Itt,Tix	Si-N	=BSY 81: 80/35V	2a	TO-39	BC 141	2a	BC 140...141, BSW 65...68, BSX 45...47, ++
BSY 84	Itt,Tix	Si-N	=BSY 81: 80/35V, 120MHz, hFE=100...300	2a	TO-39	BC 141	2a	BC 140...141, BSW 65...68, BSX 45...47, ++
BSY 85	Itt,Tix	Si-N	=BSY 81: 120/64V, 110MHz	2a	TO-39	BC 141	2a	BSS 42...43, BSW 67...68, BSX 47, 2N2102++
BSY 86	Itt,Tix	Si-N	=BSY 81: 120/64V, 130MHz, hFE=100...300	2a	TO-39	(BC 141)7	2a	BSS 42...43, BSW 67...68, BSX 47, 2N2102++
BSY 87	Itt,Tix	Si-N	L.F.S, 100/60V, 0,5A, 0,8W, 100MHz, hFE=40...120	2a	TO-39	BC 141	2a	BC 141, BC 300, BSW 66...68, BSX 46...47++
BSY 88	Itt,Tix	Si-N	=BSY 87: 145MHz, hFE=100...300	2a	TO-39	BC 141	2a	BC 141, BC 300, BSW 66...68, BSX 46...47++
BSY 89	Itt,Tix	Si-N	L.F.S, Chopper, 25/18V, 0,1A, 0,3W, 80/-ns	2a	TO-18			
BSY 90	Itt,Tix	Si-N	L.F.S, 60/25V, 0,5A, 0,8W, 170MHz, F<8dB(1kHz)	2a	TO-39	BC 141	2a	BC 140...141, BC 300...302, 2N2218...19, ++
BSY 91	Aeg,Itt,Tix	Si-N	L.F.S, 40/25V, 0,3A, 0,8W, >50MHz, F<15dB(1kHz)	2a	TO-39			BC 140...141, BC 300...302, 2N2218...19, ++
BSY 92	Aeg,Tix	Si-N	=BSY 91: 60/40V	2a	TO-39			BC 140...141, BC 300...302, 2N2218...19, ++
BSY 93	Aeg,Tix	Si-N	=BSY 91: 60/40V, 0,36W	2a	TO-18			BC 337, BC 637, BSV 59, 2N2221...22, ++
BSY 95(A)	Phi,Tix,++	Si-N	H.F.S, 20/15V, 0,1A, 0,3W, >200MHz	2a	TO-18			BSW 42, BSY 62...63, 2N706A, 2N4124, ++
BSYP 62	Ucp	Si-N	N.F.S, 25V, 0,2A, 0,36W, 200MHz	2a	TO-18L			
BSYP 63	Ucp	Si-N	N.F.S, 40V, 0,2A, 0,36W, 300MHz	2a	TO-18L			

BT								
BT		Si-P	=2SB1048 (SMD-Marking)	39	SOT-89			+2SB1048
BT		Si-N	=2SC4069 (SMD-Marking)	35	SOT-23			+2SC4069
BT		Si-P	=BCW 61RE (SMD-Marking)	35	SOT-23			+BCW 61RE
BT 1		Si-P	=BSP 15 (SMD-Marking)	=39°	SOT-223			+BSP 15
BT 1		Si-P	=BST 15 (SMD-Marking)	=39°	SOT-89			+BST 15
BT 2		Si-P	=BSP 16 (SMD-Marking)	=39°	SOT-223			+BSP 16
BT 2		Si-P	=BST 16 (SMD-Marking)	39	SOT-89			+BST 16
BT 100 A/...R	Phi	50Hz-Thy	300...500V, 2A(Tc=75°), 4,5A=, Igt/Ih<10/<15mA	13k	TO-202	TAG 626-600 ⁴	17e	(TAG 631..., TAG 632..., TAG 621...,++) ⁴
BT 101/300...500 R	Phi	50Hz-Thy	300...500V, 6,5A(Tc=85°), 15A=, Igt<10	21b	TO-64			
BT 102/...R	Phi	50Hz-Thy	=BT 101/...R: Igt<50mA	21b	TO-64			BTW 42/...
BT 103	Itt	GTO-Thy	1100V, 2,6A(Tc=85°C), Igt<100mA, <1µs	22a	TO-66			
BT 104	Itt	GTO-Thy	1200V, 3A(Tc=85°C), Igt<100mA, <1µs	22a	TO-66			
BT 105	Itt	GTO-Thy	600V, 2,7A(Tc=85°C), Igt<100mA, <1µs	22a	TO-66			
BT 106	Phi	F-Thy	700V, 1A(Tc=90°C), Igt/Ih<20/<25mA, 17µs	21b	TO-64			
BT 106 A...D	Phi	50Hz-Thy	100...400V, 4A=, Igt/Ih<0,2/<3mA A=100V, B=200V, C=300V, D=400V	14e	TO-126	TIC 106 M ⁴	16e	C 106 A, 2N6236...6241, (TIC 106...) ⁴
BT 107	Phi	Thy	500V, 6,5A(Tc=60°C), Igt<10mA	21b	TO-64			
BT 108	Phi	Thy	500V, 6,5A(Tc=60°C), Igt<50mA	21b	TO-64			BTW 42/600
BT 109	Phi	Thy	500V, 6,5A(Tc=75°C), Igt/Ih<10/<50mA	21b	TO-64			
BT 109/...R		Thy				TAG 626-600	17e	BST C0246
BT 110	Phi	Thy	400V, 6A(Tc=75°C), Igt/Ih<35/<20mA					
BT 112/750R	Tho	F-Thy	TV-HA, 750V, 3,2A(Tc=60°), 5A=, Igt<50mA, <2,4µs	22a	TO-66	TD 3FP 800H1*	17f	S 3703 SF, TU 3F 800H, (TD 3F 800 H) ¹
BT 113/700R	Tho	F-Thy	TV-HA, 700V, 3,2A(Tc=60°), 5A=, Igt<50mA, <4,5µs	22a	TO-66	TD 3FP 800R1*	17f	S 3702 S, S 6080 C, (TD 3F 800 R) ¹
BT 114	Ssc	F-Thy	TV-HA, 750V, 3,2A(Tc=60°), Igt<50mA, <2,4µs			TD 3FP 800H1*	17f	S 3703 SF, TU 3F 800H, (TD 3F 800 H) ¹
BT 114	Ssc	F-Thy	TV-HA, 700V, 3,2A(Tc=60°), Igt<50mA, <4,5µs			TD 3FP 800R1*	17f	S 3702 S, S 6080 C, (TD 3F 800 R) ¹
BT 116	Phi	Thy	750V, 1A(Tc=100°C), 15A=, Igt<20mA					